

# SILICON POWER TRANSISTOR 2SC4554

# NPN SILICON EPITAXIAL TRANSISTOR FOR SWITCHING

The 2SC4554 is a power transistor designed especially for low collector saturation voltage and features large current switching at a low power dissipation.

In addition, a high hee enables alleviation of the driver load.

#### **FEATURES**

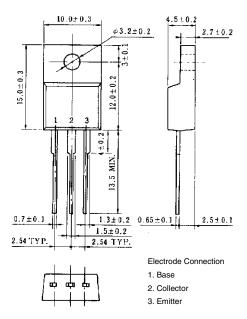
- High hre and low VcE(sat): hre  $\cong 800$  (VcE = 2 V, Ic = 5 A)  $VcE(sat) \cong 0.12$  V (Ic = 5 A, IB = 0.05 A)
- On-chip C to E damper diode
- Mold package that does not require an insulating board or insulation bushing

### ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

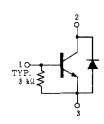
Parameter	Symbol	Ratings	Unit	
Collector to base voltage	V <sub>СВО</sub>	100	V	
Collector to emitter voltage	VCEO	100	V	
Emitter to base voltage	V <sub>EBO</sub>	7.0	V	
Collector current (DC)	Ic(DC)	±15	Α	
Collector current (pulse)	Ic(pulse)*	±22	Α	
Base current (DC)	I <sub>B(DC)</sub>	4.0	Α	
Total power dissipation	P <sub>T</sub> (Tc = 25°C)	35	W	
Total power dissipation	P⊤ (Ta = 25°C)	2.0	W	
Junction temperature	Tj	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

<sup>\*</sup> PW  $\leq$  10 ms, duty cycle  $\leq$  50%

#### PACKAGE DRAWING (UNIT: mm)



#### **EQUIVALENT CIRCUIT**



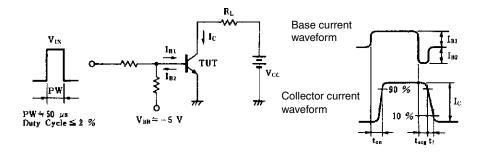
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### **ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

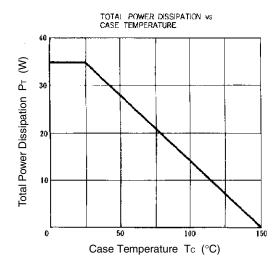
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	VcB = 100 V, IE = 0			10	μΑ
Emitter cutoff current	ІЕВО	V <sub>EB</sub> = 5.0 V, I <sub>C</sub> = 0			17	mA
DC current gain	h <sub>FE1</sub>	VcE = 2.0 V, Ic = 5.0 A	450	800	2,000	
DC current gain	h <sub>FE2</sub>	VcE = 2.0 V, Ic = 10 A	150			
Collector saturation voltage	VCE(sat)1	Ic = 5.0 A, I <sub>B</sub> = 100 mA			0.25	V
Collector saturation voltage	VCE(sat)2	Ic = 5.0 A, I <sub>B</sub> = 50 mA		0.12	0.3	V
Collector saturation voltage	VCE(sat)3	Ic = 10 A, I <sub>B</sub> = 200 mA			0.4	V
Collector saturation voltage	VCE(sat)4	Ic = 10 A, I <sub>B</sub> = 100 mA			0.75	V
Base saturation voltage	V <sub>BE(sat)</sub>	Ic = 10 A, I <sub>B</sub> = 100 mA			1.2	V
Gain bandwidth product	f⊤	VcE = 5.0 V, Ic = 1.0 A		100		MHz
Collector capacitance	Cob	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz		210		pF
Turn-on time	ton	Ic = 8.0 A, R <sub>L</sub> = 2.0 $\Omega$ , I <sub>B1</sub> = -I <sub>B2</sub> = 80 mA, V <sub>CC</sub> $\cong$ 16 V Refer to the test circuit.		0.5		μs
Storage time	tstg			2.0		μs
Fall time	tr			0.5		μs
Diode forward voltage	V <sub>DF</sub>	IDF = 10 A		1.6		V

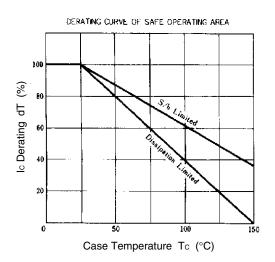
## SWITCHING TIME (ton, tstg, tf) TEST CIRCUIT

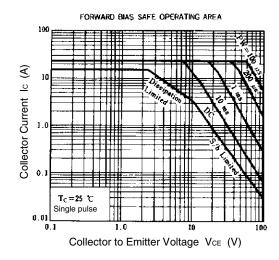


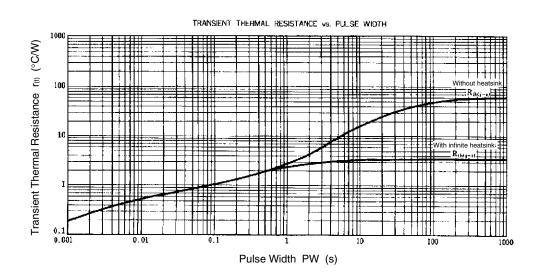


### TYPICAL CHARACTERISTICS (Ta = 25°C)



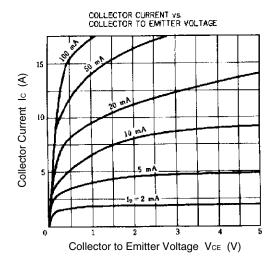


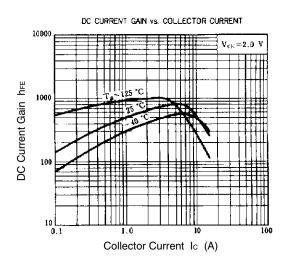


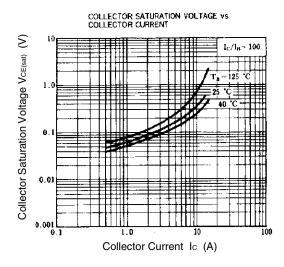


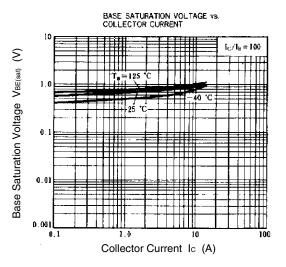
Data Sheet D15600EJ2V0DS

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